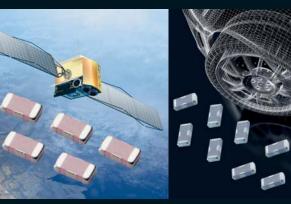
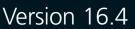
AVX Multilayer Ceramic SMD Feedthru Capacitors









www.avx.com



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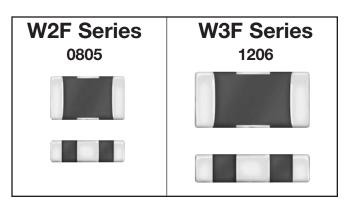
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W2F/W3F Series

GENERAL DESCRIPTION

Available in both a standard 0805 and 1206 size, AVX's line of feedthru capacitors are ideal choices for EMI suppression, broadband I/O filtering, or Vcc power line conditioning. The unique construction of a feedthru capacitor provides low parallel inductance and offers excellent decoupling capability for all high di/dt environments and provides significant noise reduction in digital circuits to <5 GHz. A large range of capacitor values are available in either NPO or X7R ceramic dielectrics. AVX FeedThru filters are AEC Q200 qualified. High reliability screening options are available for spacecraft designs.



SIGNAL LINE - INPUT > OUTPUT

CAPACITOR VALUES

Part Number	Size	Voltage	Dielectric	Capacitance
W2F11A 220 8ATxx	0805	100V	NP0	22pF
W2F11A 470 8ATxx	0805	100V	NP0	47pF
W2F11A 101 8ATxx	0805	100V	NP0	100pF
W2F11A 221 8ATxx	0805	100V	NPO	220pF
W2F11A 471 8ATxx	0805	100V	NPO	470pF
W2F15C 102 8ATxx	0805	50V	X7R	1000pF
W2F15C 222 8ATxx	0805	50V	X7R	2200pF
W2F15C 472 8ATxx	0805	50V	X7R	4700pF
W2F15C 103 8ATxx	0805	50V	X7R	10000pF
W2F15C 223 8ATxx	0805	50V	X7R	22000pF
W2F15C 473 8ATxx	0805	50V	X7R	47000pF
W3F11A 220 8ATxx	1206	100V	NPO	22pF
W3F11A 470 8ATxx	1206	100V	NPO	47pF
W3F11A 101 8ATxx	1206	100V	NPO	100pF
W3F11A 221 8ATxx	1206	100V	NP0	220pF
W3F11A 471 8ATxx	1206	100V	NPO	470pF
W3F15C 102 8ATxx	1206	50V	X7R	1000pF
W3F15C 222 8ATxx	1206	50V	X7R	2200pF
W3F15C 472 8ATxx	1206	50V	X7R	4700pF
W3F15C 103 8ATxx	1206	50V	X7R	10000pF
W3F15C 223 8ATxx*	1206	50V	X7R	22000pF
W3F15C 473 8ATxx	1206	50V	X7R	47000pF

PERFORMANCE CHARACTERISTICS

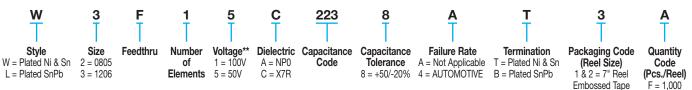
	NP0	X7R	
Capacitance Tolerance	+50%, -20%	+50%, -20%	
Voltage Rating	100V	50V	
Current Rating	300mA	300mA	
Insulation Resistance	1000MΩ	1000ΜΩ	
DC Resistance	<0.6Ω	<0.6Ω	
Operating Temperature Range	-55 to +125°C		



3 & 4 = 13" Reel

Embossed Tape

HOW TO ORDER



*AECQ-200 Qualified. Contact factory for other values.

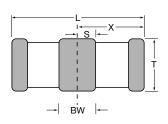
**Note: NP0 available in 100V only and X7R available in 50V only.

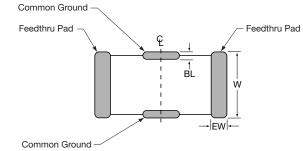
A = 2,000,

4,000 or 10.000



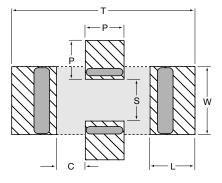
W2F/W3F Series





DIMENSIONS

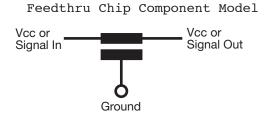
	L	w	т	BW	BL	EW	х	S
0805 MM	2.01 ± 0.20	1.25 ± 0.20	1.14 Max.	0.46 ± 0.10	0.18 + 0.25 -0.08	0.25 ± 0.13	1.02 ± 0.10	0.23 ± 0.15
(in.)	(0.079 ± 0.008)	(0.049 ± 0.008)	(0.045 Max.)	(0.018 ±0.004)	(0.007 + 0.010 -0.003)	(0.010 ± 0.005)	(0.040 ± 0.004)	(0.009 ± 0.006)
1206 MM	3.20 ± 0.20	1.60 ± 0.20	1.27 Max.	0.89 ± 0.10	0.18 + 0.25 -0.08	0.38 ± 0.18	1.60 ± 0.10	0.46 ± 0.15
(in.)	(0.126 ± 0.008)	(0.063 ± 0.008)	(0.050 Max.)	(0.035 ± 0.004)	(0.007 + 0.010 -0.003)	(0.015 ± 0.007)	(0.063 ± 0.004)	(0.018 ± 0.006)



RECOMMENDED SOLDER PAD LAYOUT (TYPICAL DIMENSIONS)

	Т	Р	S	W	L	С
0805 MM	3.45	0.51	0.76	1.27	1.02	0.46
(in.)	(0.136)	(0.020)	(0.030)	(0.050)	(0.040)	(0.018)
1206 MM	4.54	0.94	1.02	1.65	1.09	0.71
(in.)	(0.179)	(0.037)	(0.040)	(0.065)	(0.043)	(0.028)

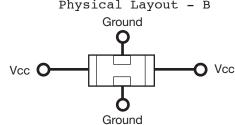
TYPICAL FEEDTHRU CHIP CAP CONNECTION



Physical Layout - A Ground Signal In O Signal Out Ground Physical Layout - B Ground

The terminals are connected internally side to side. Left side and right side are connected and front and back are connected internally. For Decoupling, the chip is usually surrounded by

For Decoupling, the chip is usually surrounded by four vias, two for Vcc and two for GND. For Signal Filtering, the in and out lines need to be separated on the circuit board.

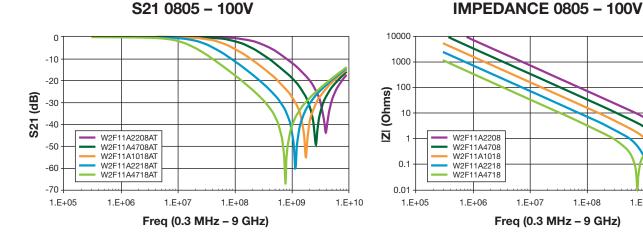




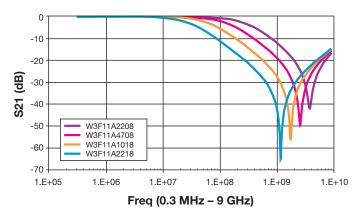


W2F/W3F Series

PERFORMANCE CHARACTERISTICS



S21 1206 - 100V

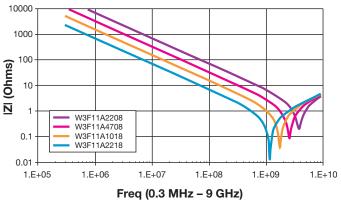


IMPEDANCE 1206 – 100V

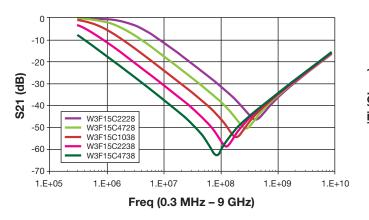
1.E+08

1.E+09

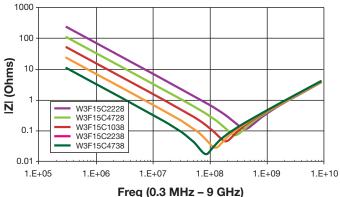
1.E+10



S21 1206 - 50V



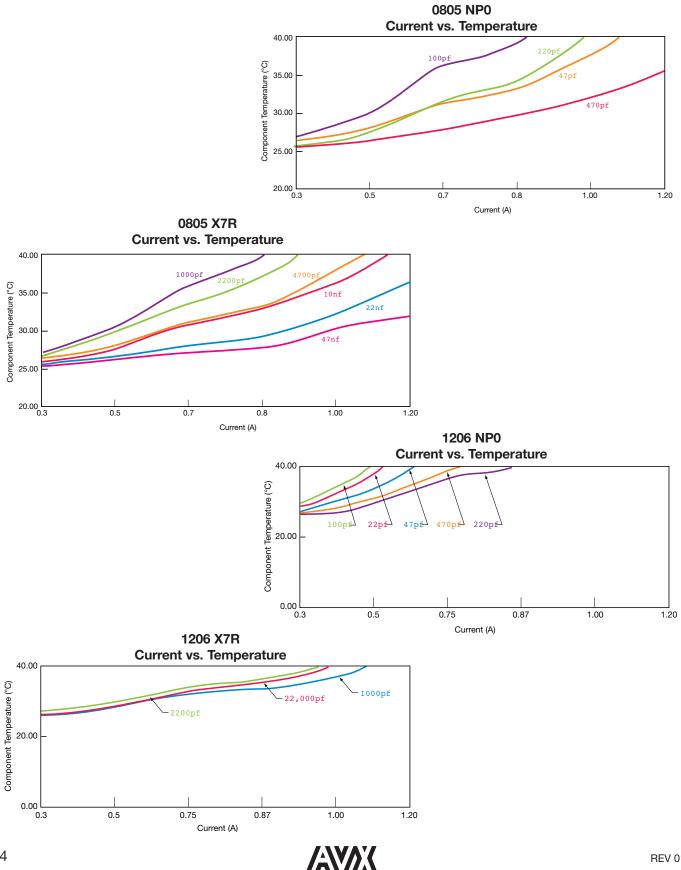
IMPEDANCE 1206 – 50V





W2F/W3F Series

PERFORMANCE CHARACTERISTICS



Feedthru 0805/1206 Tin/Lead Capacitors



L2F/L3F Series

GENERAL DESCRIPTION

Available in both a standard 0805 and 1206 size, AVX's line of feedthru capacitors are ideal choices for EMI suppression, broadband I/O filtering, or Vcc power line conditioning. The unique construction of a feedthru capacitor provides low parallel inductance and offers excellent decoupling capability for all high di/dt environments and provides significant noise reduction in digital circuits to <5 GHz. A large range of capacitor values are available in either NPO or X7R ceramic dielectrics.

SIGNAL LINE - INPUT > OUTPUT GROUND



CAPACITOR VALUES

Part Number	Size	Voltage	Dielectric	Capacitance
L2F11A 220 8ATxx	0805	100V	NP0	22pF
L2F11A 470 8ATxx	0805	100V	NPO	47pF
L2F11A 101 8ATxx	0805	100V	NP0	100pF
L2F11A 221 8ATxx	0805	100V	NPO	220pF
L2F11A 471 8ATxx	0805	100V	NP0	470pF
L2F15C 102 8ATxx	0805	50V	X7R	1000pF
L2F15C 222 8ATxx	0805	50V	X7R	2200pF
L2F15C 472 8ATxx	0805	50V	X7R	4700pF
L2F15C 103 8ATxx	0805	50V	X7R	10000pF
L2F15C 223 8ATxx	0805	50V	X7R	22000pF
L2F15C 473 8ATxx	0805	50V	X7R	47000pF
L3F11A 220 8ATxx	1206	100V	NP0	22pF
L3F11A 470 8ATxx	1206	100V	NPO	47pF
L3F11A 101 8ATxx	1206	100V	NPO	100pF
L3F11A 221 8ATxx	1206	100V	NP0	220pF
L3F11A 471 8ATxx	1206	100V	NP0	470pF
L3F15C 102 8ATxx	1206	50V	X7R	1000pF
L3F15C 222 8ATxx	1206	50V	X7R	2200pF
L3F15C 472 8ATxx	1206	50V	X7R	4700pF
L3F15C 103 8ATxx	1206	50V	X7R	10000pF
L3F15C 223 8ATxx	1206	50V	X7R	22000pF
L3F15C 473 8ATxx	1206	50V	X7R	47000pF

PERFORMANCE CHARACTERISTICS

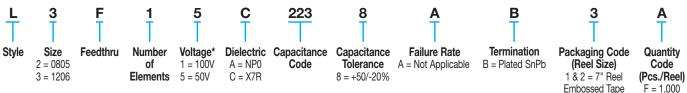
	NP0	X7R	
Capacitance Tolerance	+50%, -20%	+50%, -20%	
Voltage Rating	100V	50V	
Current Rating	300mA	300mA	
Insulation Resistance	1000MΩ	1000ΜΩ	
DC Resistance	<0.6Ω	<0.6Ω	
Operating Temperature Range	-55 to +125°C		

Not RoHS Compliant

3 & 4 = 13" Reel

Embossed Tape

HOW TO ORDER



*Note: NP0 available in 100V only and X7R available in 50V only.



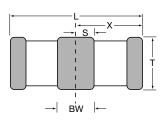
A = 2,000,

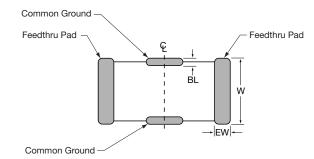
4,000 or

10,000

Feedthru 0805/1206 Tin/Lead Capacitors

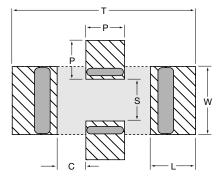
L2F/L3F Series





DIMENSIONS

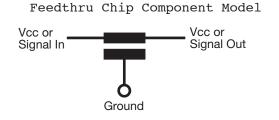
	L	w	т	BW	BL	EW	х	S
0805 MM	2.01 ± 0.20	1.25 ± 0.20	1.14 Max.	0.46 ± 0.10	0.18 + 0.25 -0.08	0.25 ± 0.13	1.02 ± 0.10	0.23 ± 0.15
(in.)	(0.079 ± 0.008)	(0.049 ± 0.008)	(0.045 Max.)	(0.018 ±0.004)	(0.007 + 0.010 -0.003)	(0.010 ± 0.005)	(0.040 ± 0.004)	(0.009 ± 0.006)
1206 MM	3.20 ± 0.20	1.60 ± 0.20	1.27 Max.	0.89 ± 0.10	0.18 + 0.25 -0.08	0.38 ± 0.18	1.60 ± 0.10	0.46 ± 0.15
(in.)	(0.126 ± 0.008)	(0.063 ± 0.008)	(0.050 Max.)	(0.035 ± 0.004)	(0.007 + 0.010 -0.003)	(0.015 ± 0.007)	(0.063 ± 0.004)	(0.018 ± 0.006)



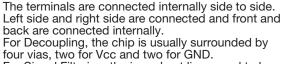
RECOMMENDED SOLDER PAD LAYOUT (TYPICAL DIMENSIONS)

	Т	Р	S	W	L	С
0805 MM	3.45	0.51	0.76	1.27	1.02	0.46
(in.)	(0.136)	(0.020)	(0.030)	(0.050)	(0.040)	(0.018)
1206 MM	4.54	0.94	1.02	1.65	1.09	0.71
(in.)	(0.179)	(0.037)	(0.040)	(0.065)	(0.043)	(0.028)

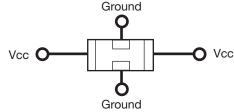
TYPICAL FEEDTHRU CHIP CAP CONNECTION



Physical Layout - A Ground Signal In O Signal Out Ground Physical Layout - B Ground O



For Signal Filtering, the in and out lines need to be separated on the circuit board.





High Current Feedthru Capacitors



GENERAL DESCRIPTION

High current feedthru capacitors are designed as a broadband EMI filter that is specially designed to have high current handling capability. These SMT feedthru filters offer an optimized frequency response with high attenuation across a wide RF spectrum due to optimized parallel and series inductances. These W2H feedthru filters can actually replace discrete L/C filter networks.

FEATURES

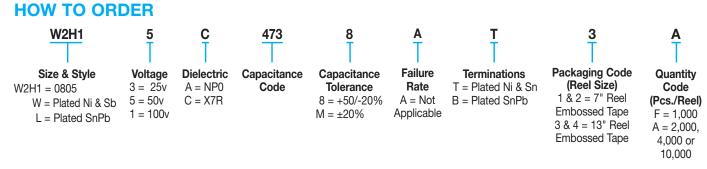
- Low parallel inductance provides significant noise reduction in circuits with operating frequencies up to 5GHz
- Broad frequency response with high attenuation
- High rated current up to 2A for 080
- Small size 0805
- Reeling in accordance with EIA-481

MECHANICAL CHARACTERISTICS

- Available in EIA 0805
- Plated Tin over Nickel Barrier
- Packaged in Tape & Reel

TYPICAL APPLICATIONS

- High current power (Vcc) lines
- PA decoupling
- DC:DC converters
- Regulators
- Power supervisory circuits

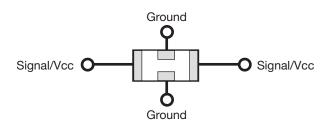






7

PINOUT CONFIGURATION



W2H1 – 0805 Style



High Current Feedthru Capacitors W2H



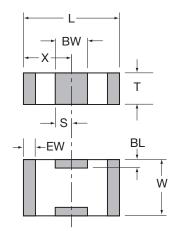
ELECTRICAL PARAMETERS

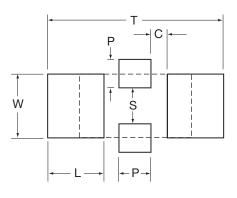
Insulation Resistance	1000 MΩ Minimum
DC Resistance	<0.150 Ω
Operating Temperature	-55C to +125C

CAPACITOR VALUES

Part Number	Size	Dielectric	Capacitance	Tolerance	Voltage	Current
W2H13C 104 8AT	0805	X7R	100,000pF	+50%, -20%	25V	2A
W2H15C 473 8AT	0805	X7R	47,000pF	+50%, -20%	50V	2A
W2H15C 223 8AT	0805	X7R	22,000pF	+50%, -20%	50V	1A
W2H15C 103 8AT	0805	X7R	10,000pF	+50%, -20%	50V	1A
W2H15C 102 8AT	0805	X7R	1,000pF	+50%, -20%	50V	1A
W2H11A 471 8AT	0805	NP0	470pF	+50%, -20%	100V	0.5A
W2H11A 221 8AT	0805	NP0	220pF	+50%, -20%	100V	0.5A
W2H11A 101 8AT	0805	NP0	100pF	+50%, -20%	100V	0.5A
W2H11A 470 8AT	0805	NP0	47pF	+50%, -20%	100V	0.5A
W2H11A 220 8AT	0805	NP0	22pF	+50%, -20%	100V	0.5A

PHYSICAL DIMENSIONS AND PAD LAYOUT





W2H1 - 0805 Style

PHYSICAL DIMENSIONS

	L	W	Т	BW	BL	ES	EW	х	S
W2H1- 0805 MM (in.)		1.25 ± 0.20 (0.049 ± 0.008)	1.14 Max. (0.045 Max.)	0.46 ± 0.10 (0.018 ±0.004)	0.18 + 0.25 -0.08 (0.007 + 0.010 -0.003)	NA	0.25 ± 0.13 (0.010 ± 0.005)	1.02 ± 0.10 (0.040 ± 0.004)	0.23 ± 0.05 (0.009 ± 0.002)

PAD DIMENSIONS

	т	Р	S	w	L	С	х
W2H1- 0805 MM	3.45	0.51	0.76	1.27	1.02	0.46	NA
(in.)	(0.136)	(0.020)	(0.030)	(0.050)	(0.040)	(0.018)	

W2F/W3F Series



APPLICATIONS

EMI Suppression Broadband I/O Filtering Vcc Line Conditioning

Applications

FEATURES

Standard EIA Sizes Broad Frequency Response Low ESR 8 mm Tape and Reel

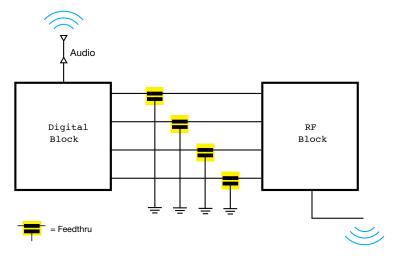
MARKET SEGMENTS

Computers Automotive Power Supplies Multimedia Add-On Cards Bar Code Scanners and Remote Terminals PCMCIA Cards Medical Instrumentation Test Equipment Transceivers/Cell Phones

Typical Circuits Requiring EMI Filtering

THE FOLLOWING APPLICATIONS AND SCHEMATIC DIAGRAMS SHOW WHERE FEEDTHRU CAPACITORS MIGHT BE USED FOR EMI SUPPRESSION

- Digital to RF Interface Filtering
- Voltage Conditioning in RF Amplifiers
- Power Decoupling GaAs FET Transistor Preamplifier
- Vcc Line Filtering on Frequency Control Circuit
- Clock, Data, Control Line High Frequency Decoupling (Frequency Synthesizer) (SEE APPLICATION NOTES)

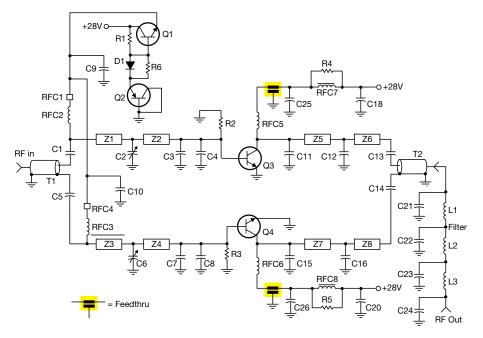


DIGITAL TO RF INTERFACE FILTERING

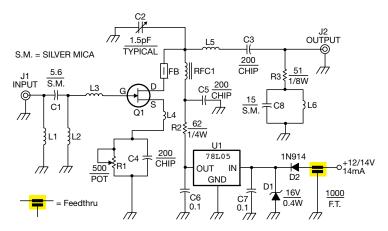


W2F/W3F Series

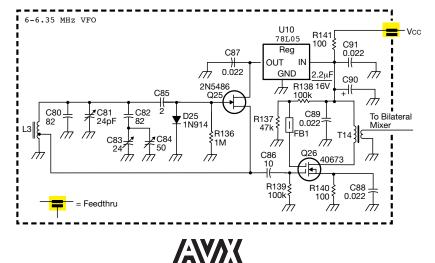




POWER DECOUPLING GaAs FET TRANSISTOR PREAMPLIFIER



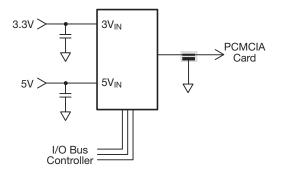
Vcc LINE FILTERING ON FREQUENCY CONTROL CIRCUIT

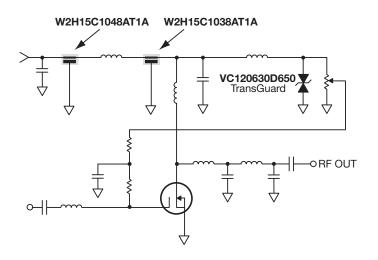




APPLICATIONS

Dual Power Switch Filtering





PA Filtering





EMI REDUCTION THROUGH THE USE OF SMT FEEDTHRU CAPACITORS

ABSTRACT

Today's high speed, miniaturized semiconductors have made EMI issues a key design consideration. This paper briefly defines EMI and illustrates the capability of SMT feedthru capacitors.

WHAT IS EMI?

The term EMI stands for Electromagnetic Interference and refers to signals/energy interfering with a circuit or systems functions.

In an electronic system, two classes of energy are generated - wanted and unwanted. Both are potential sources of EMI⁽¹⁾.

Wanted signals such as clocks and bus lines could cause EMI if they were not decoupled, terminated or filtered properly. Unwanted signals (cell phones, police radios, power supply noise, etc.) could be conducted or radiated into the circuit due to poor circuit layout, improper decoupling or a lack of high frequency filtering.

In either type of EMI signal interference, the system could be rendered useless or put into a state which would cause early failure of its semiconductors. Even worse, the unwanted energy could cause an incorrect answer to be generated from a computer by randomly powering a gate up or down.

From all of this we can gather that EMI is a complex problem, usually with no one solution. EMI interference can be a random single shot noise (like a SCR firing) or repetitive in nature (stepper motor or relay noise). The interference can enter into our designs either by being induced by E/B fields, or it can be conducted through control lines or a communication bus. EMI can even be self generated by internal components that generate steep risetime waveforms of voltage or current.

HOW CAN EMI BE CONTROLLED?

EMI is most efficiently controlled by realizing it to be a design parameter in the earliest stages of the design. This way, the board layout can be optimized with large power and ground planes which will be low impedance in nature. The use of SMT feedthru filters will yield optimal results.

SMT FEEDTHRU CAPACITORS

AVX introduced feedthru capacitors to supply a broadband EMI filter capacitor for source suppression and receiver noise reduction.

SMT feedthru capacitors use the same material systems as standard ceramic capacitors. They exhibit the same reliabili-

(1)Practical Design for Electromagnetic Compatibility edited by Rocco F. Ficchi Hayden Book Company 1978 ty and can be processed in the same end user production methods as standard capacitors. What feedthru capacitors offer is an optimized frequency response across a wide RF spectrum due to a modified internal electrode design.

An application comparison between an SMT feedthru and a discrete capacitor is shown in Figure 1.



Figure 1. Comparison of Feedthru Capacitors to Discrete Capacitors

The key difference between the two filtering methods is that the feedthru has a much lower inductance between the signal line and ground than the capacitor. The difference in inductances can be in the range of roughly one order magnitude with a feedthru capacitor. This inductance can be shown in an electrical sense through the model for a feedthru and a capacitor (Figure 2).

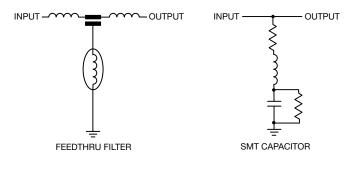


Figure 2. Comparison of Feedthru Capacitors to Discrete Capacitors

The feedthru capacitor has a minimized <u>parallel</u> inductance and an optimal <u>series</u> inductance (which broadens the frequency response curve). Typical attenuation graphs are shown in Figure 3A.

These curves demonstrate feedthru capacitors advantage of a broad frequency response with high attenuation. They also serve as a comparison to the inductance of even lower inductance devices (primarily used in extreme decoupling cases and switch mode power supplies) - see Figure 3B.





W2F/W3F Series

W3F15C2228AT High Frequency Analysis

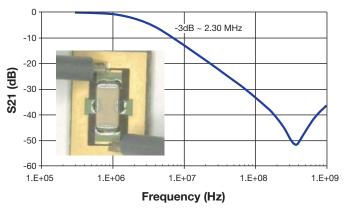


Figure 3A. Typical Attenuation Graph

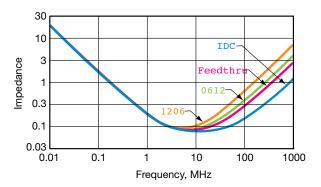


Figure 3B. Comparison of SMT Capacitor Frequency Response to Feedthru Filters

SMT FEEDTHRU CAPACITOR TERMINOLOGY

AVX's feedthru capacitors have additional technical terminologies relative to standard ceramic capacitors. The reason for this is due to the series manner in which the feedthru element is connected to the circuit.

The most important term is <u>DC Resistance</u>. The DC resistance of the feedthru is specified since it causes a minor signal attenuation which designers can calculate by knowing the maximum resistance of the part.

The maximum current capability of the part is also of interest to designers since the feedthru may be placed in series with the voltage line.

APPLICATION AND SELECTION OF SMT FEEDTHRU CAPACITOR FILTERS

EMI suppression and receiver noise reduction can be achieved most effectively with efficient filtering methods. Attenuations of over 100 dB are achievable depending on the complexity and size of the filters involved.

However, before filtering is discussed, another EMI reduction method is noise limiting, using a series element (inductors or resistors). This method is easy to implement and inexpensive. The problem it poses is that it can only reduce noise by -3 to -10 dB. Because of that, series element EMI reduction is primarily used where there is a poor ground.

SMT feedthru filter capacitors can actually replace discrete L/C filter networks (depending on the frequency response needed). The SMT filter capacitors should first be chosen for its specific frequency response. Then the voltage rating, DCR, and current capability must be evaluated for circuit suitability. If there is not a match on voltage, current and DC resistance ratings, the designer must select the closest available frequency response available on parts that will meet the design's power spec.

The top 5 applications for SMT feedthru filter capacitors are:

- 1. Digital to RF interface filtering.
- 2. Control line high frequency decoupling.
- 3. Data and clock high frequency decoupling.
- 4. Power line high frequency decoupling.
- 5. High gain and RF amplifier filtering.

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